

RELIABILITY REPORT
FOR
MAXM17514ALI+
PLASTIC ENCAPSULATED DEVICES

March 19, 2015

MAXIM INTEGRATED

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Conclusion

The MAXM17514ALI+ successfully meets the quality and reliability standards required of all Maxim Integrated products. In addition, Maxim Integrated's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim Integrated's quality and reliability standards.

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I. Device Description

A. General

The MAXM17514 is a fixed-frequency, step-down power module in a thermally-efficient system-in-package (SiP) package that operates from a 2.4V to 5.5V input supply voltage and supports output currents up to 4A. The device includes switch-mode power-supply controller, dual n-channel MOSFET power switches, a fully shielded inductor, as well as compensation components. The device supports 0.75V to 3.6V programmable output voltage. The high level of integration significantly reduces design complexity, manufacturing risks, and offers a true plug-and-play power-supply solution, reducing the time to market. The MAXM17514 is available in a thermally enhanced, compact 28-pin, 10mm x 6.5mm x 2.8mm SiP package and can operate over the -40°C to +125°C industrial temperature range.



II. Manufacturing Information

A. Description/Function: 4A, 2.4V to 5.5V Input, High-Efficiency Power Module

B. Process: S4C. Fabrication Location: USAD. Assembly Location: Taiwan

E. Date of Initial Production: December 17, 2014

III. Packaging Information

A. Package Type: 28-pin, 10mm x 6.5mm x 2.8mm SiP

B. Lead Frame: Copper
C. Lead Finish: AuNi
D. Die Attach: Conductive
E. Bondwire: Au (2 mil dia.)
F. Mold Material: Epoxy with silica filler

G. Assembly Diagram: #31-4927
 H. Flammability Rating: Class UL94-V0
 I. Classification of Moisture Sensitivity Level 3

I. Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C

J. Single Layer Theta Ja: N/A°C/W
K. Single Layer Theta Jc: N/A°C/W
L. Multi Layer Theta Ja: 33.56°C/W
M. Multi Layer Theta Jc: 33.55°C/W

IV. Die Information

A. Dimensions: 39.3701X39.3701 mils

B. Passivation: Si₃N₄/SiO₂ (Silicon nitride/ Silicon dioxide)

C. Interconnect: Al/0.5%Cu with Ti/TiN Barrier

D. Backside Metallization: None

E. Minimum Metal Width: 0.4 microns (as drawn)F. Minimum Metal Spacing: 0.6 microns (as drawn)

G. Bondpad Dimensions:

H. Isolation Dielectric: SiO₂I. Die Separation Method: Wafer Saw



V. Quality Assurance Information

A. Quality Assurance Contacts: Don Lipps (Manager, Reliability Engineering)

Bryan Preeshl (Vice President of QA)

B. Outgoing Inspection Level: 0.1% for all electrical parameters guaranteed by the Datasheet.

0.1% for all Visual Defects.

C. Observed Outgoing Defect Rate: < 50 ppmD. Sampling Plan: Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

$$\frac{1}{MTTF} = \frac{1.83}{192 \times 4340 \times 150 \times 2}$$
 (Chi square value for MTTF upper limit)
where 4340 = Temperature Acceleration factor assuming an act

(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)

$$\lambda = 1.4 \text{ x } 10^{-9}$$

 $\lambda = 1.4 \text{ F.I.T.}$ (60% confidence level @ 25°C)

The following failure rate represents data collected from Maxim Integrated's reliability monitor program. Maxim Integrated performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maximintegrated.com/qa/reliability/monitor. Cumulative monitor data for the S4 Process results in a FIT Rate of 0.04@ 25°C and 0.69 @ 55°C (0.8 eV, 60% UCL)

B. E.S.D. and Latch-Up Testing

The PI22-2 die type has been found to have all pins able to withstand an HBM transient pulse of +/-2500V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250mA and overvoltage per JEDEC JESD78.



Table 1Reliability Evaluation Test Results

MAXM17514ALI+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	COMMENTS
Static Life Test (Not	e 1) Ta = 135°C Biased Time = 192 hrs.	DC Parameters & functionality	150	0	

Note 1: Life Test Data may represent plastic DIP qualification lots.